

CCG3-48-xxD

EVALUATION DATA

型式データ

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使用記号 Terminology used

	定義	Definition
V_{in}	入力電圧 Input voltage
$+V_o, -V_o$	出力電圧 Output voltage
V_{RC}	RC電圧 RC voltage
I_{in}	入力電流 Input current
$+I_o, -I_o$	出力電流 Output current
T_a	周囲温度 Ambient temperature
f	周波数 Frequency

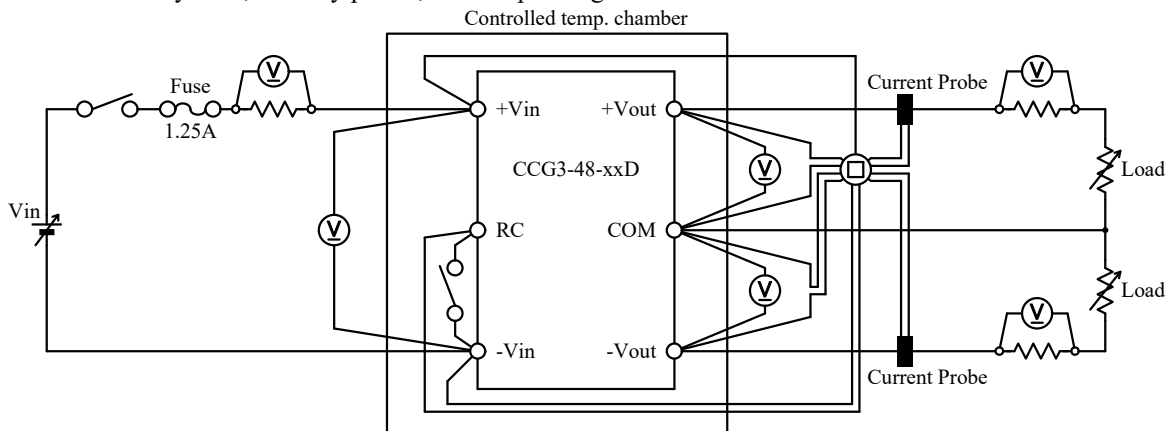
※ 当社測定条件における結果であり、参考値としてお考え願います。
Test results are reference data based on our measurement condition.

1. 測定方法 Evaluation Method

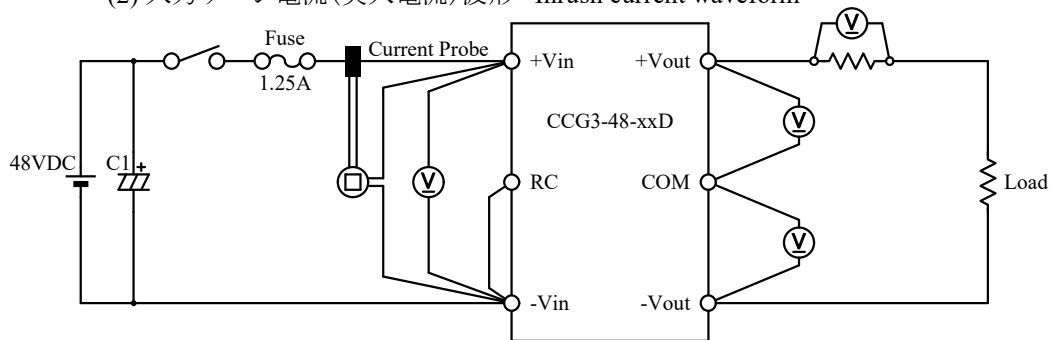
1-1. 測定回路 Measurement Circuits

(1) 静特性、待機電力特性、通電ドリフト特性、その他特性

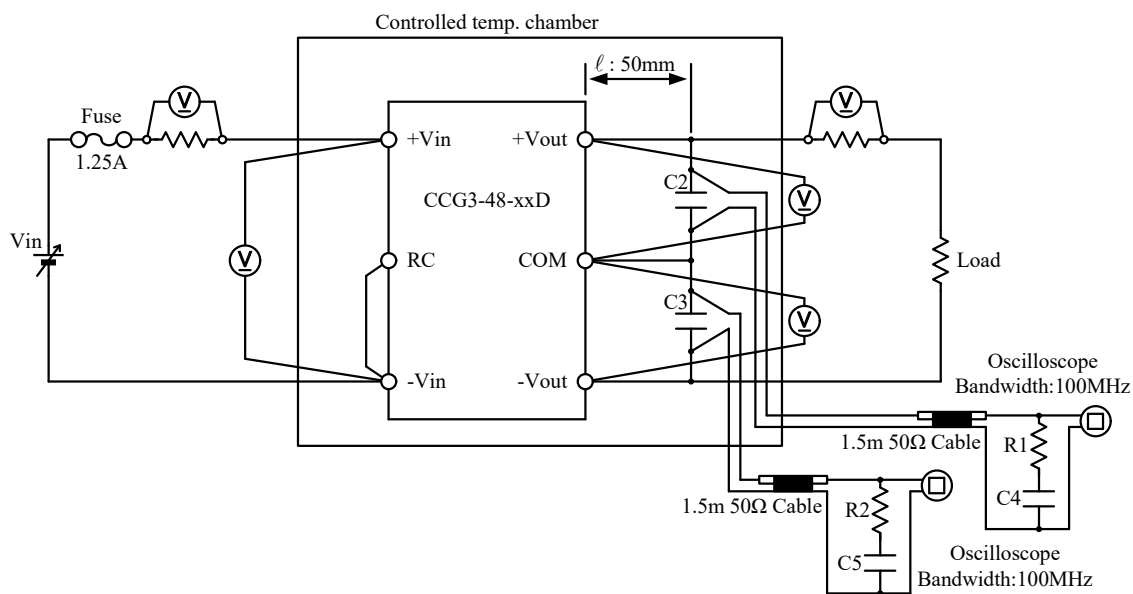
Steady state, Standby power, Warm up voltage drift and Other characteristics



(2) 入力サージ電流(突入電流)波形 Inrush current waveform



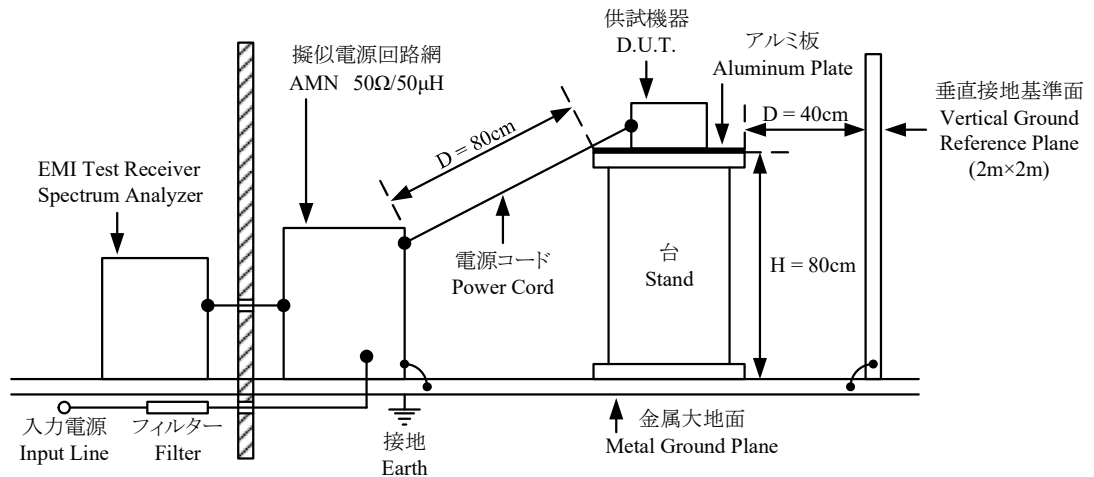
(3) 出力リップルノイズ電圧、波形 Output ripple and noise voltage and waveform



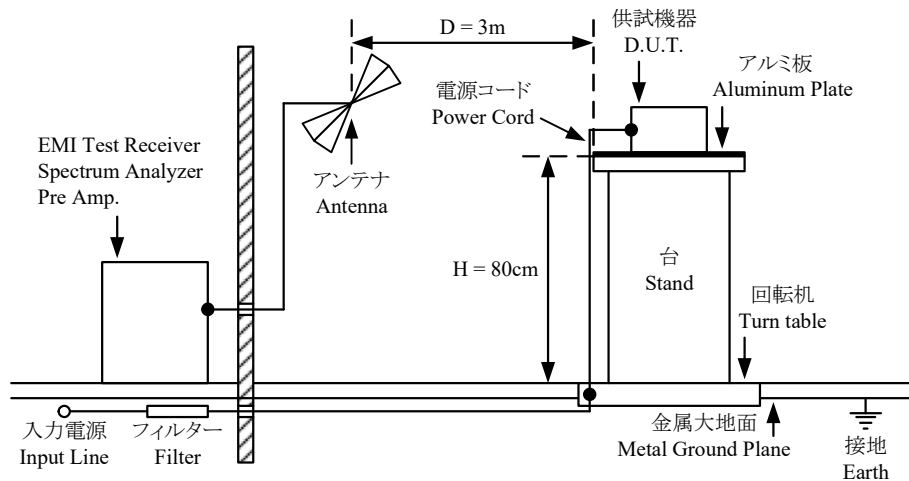
- C1 : 4000 μ F Electrolytic Capacitor
- C2, C3 : 1 μ F Ceramic Capacitor
- C4, C5 : 4700pF Ceramic Capacitor
- R1, R2 : 50 Ω

(4) EMI特性 Electro-Magnetic Interference characteristics

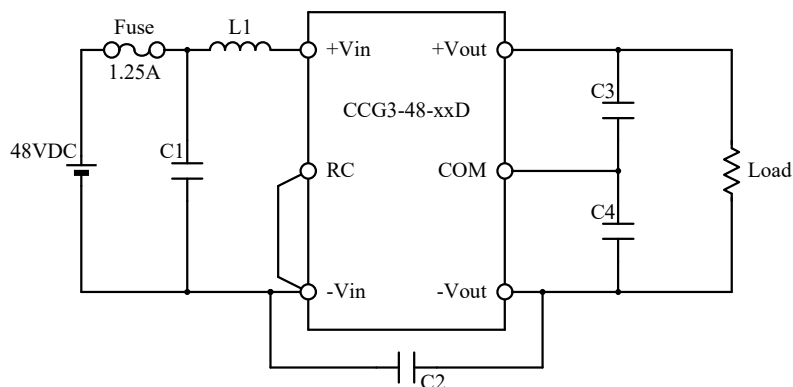
(a) 雑音端子電圧(帰還ノイズ) Conducted Emission Noise



(b) 雑音電界強度(輻射ノイズ) Radiated Emission Noise



VCCI class A 対応アプリケーション VCCI class A application system



- | | | |
|-----------------|------------------------|-------------------------|
| C1 : 100V 2.2μF | Ceramic Capacitor | (C3216X7S2A225K, TDK) |
| C2 : 2kV 1000pF | Ceramic Capacitor | (C4520X7R3D102K, TDK) |
| C3 : 25V 10μF | Ceramic Capacitor | (C3216X7R1E106K, TDK) |
| C4 : 25V 10μF | Ceramic Capacitor | (C3216X7R1E106K, TDK) |
| L1 : 22μH 650mA | Normal Mode Choke Coil | (LQH32PB220MNC, MURATA) |

1-2. 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	YOKOGAWA ELECT.	DL1740E / DL1740EL
2	DIGITAL MULTIMETER	AGILENT	34970A
3	CURRENT PROBE	YOKOGAWA ELECT.	701932
4	CURRENT PROBE	AGILENT	N2774A
5	SHUNT RESISTER	YOKOGAWA ELECT.	2215
6	DYNAMIC DUMMY LOAD	KIKUSUI	PLZ-164WL
7	CVCF	NF	ES10000S
8	DC POWER SUPPLY	TDK-Lambda	GEN80-9.5 / GENH80-9.5
9	DC POWER SUPPLY	TAKASAGO	EX-750H2
10	CONTROLLED TEMP. CHAMBER	ESPEC	SU-261 / SU-262
11	EMI TEST RECEIVER / SPECTRUM ANALYZER	ROHDE & SCHWARZ	ESR3
12	PRE AMP.	SONOMA	310N
13	AMN	KIKUSUI	KNW-242C
14	ANTENNA	SCHWARZBECK	BBA9106/VHA9103
15	ANTENNA	SCHWARZBECK	UHALP9107

2. 特性データ Characteristics

2-1. 静特性 Steady state characteristics

(1) 入力・負荷・温度変動 Regulation - line and load, Temperature drift

$\pm 12V$

1. Regulation - line and load

Condition Ta : 25 °C

•+Vo

Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	12.0358V	12.0359V	12.0365V	12.0368V	1.0mV	0.008%
50%(0.065A)	12.0340V	12.0343V	12.0334V	12.0332V	1.1mV	0.009%
100%(0.13A)	12.0255V	12.0292V	12.0329V	12.0324V	7.4mV	0.062%
Load	10.3mV	6.7mV	3.6mV	4.4mV		
regulation	0.086%	0.056%	0.030%	0.037%		

•-Vo

Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	-12.0397V	-12.0398V	-12.0392V	-12.0389V	0.9mV	0.007%
50%(0.065A)	-12.0413V	-12.0410V	-12.0422V	-12.0427V	1.7mV	0.014%
100%(0.13A)	-12.0501V	-12.0464V	-12.0431V	-12.0437V	7.0mV	0.058%
Load	10.4mV	6.6mV	3.9mV	4.8mV		
regulation	0.087%	0.055%	0.033%	0.040%		

•+Vo to -Vo

Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	24.0755V	24.0757V	24.0758V	24.0757V	0.3mV	0.001%
50%(0.065A)	24.0752V	24.0752V	24.0756V	24.0759V	0.7mV	0.003%
100%(0.13A)	24.0756V	24.0756V	24.0760V	24.0761V	0.5mV	0.002%
Load	0.4mV	0.5mV	0.4mV	0.4mV		
regulation	0.002%	0.002%	0.002%	0.002%		

2. Temperature drift

Conditions Vin : 48 VDC

Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability	
+Vo	12.0041V	12.0329V	12.0128V	28.8mV	0.240%
-Vo	-12.0076V	-12.0431V	-12.0297V	35.5mV	0.296%
+Vo to -Vo	24.0117V	24.0760V	24.0425V	64.3mV	0.268%

3. Load Regulation - Unbalance load

Condition Ta : 25 °C

•+Vo (-Io : 100%)

+Io \ Vin	18VDC	24VDC	48VDC	76VDC
20%(0.026A)	12.1421V	12.1373V	12.1373V	12.1354V
100%(0.13A)	12.0253V	12.0292V	12.0292V	12.0322V
Load	116.8mV	108.1mV	108.1mV	103.2mV
regulation	0.973%	0.901%	0.901%	0.860%

•-Vo (+Io : 100%)

-Io \ Vin	18VDC	24VDC	48VDC	76VDC
20%(0.026A)	-12.1610V	-12.1564V	-12.1564V	-12.1576V
100%(0.13A)	-12.0509V	-12.0470V	-12.0470V	-12.0442V
Load	110.1mV	109.4mV	109.4mV	113.4mV
regulation	0.917%	0.912%	0.912%	0.945%

$\pm 15V$

1. Regulation - line and load

Condition Ta : 25 °C

•+Vo

Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	14.9333V	14.9317V	14.9299V	14.9294V	3.9mV	0.026%
50%(0.05A)	14.9355V	14.9368V	14.9351V	14.9332V	3.6mV	0.024%
100%(0.1A)	14.9276V	14.9324V	14.9367V	14.9350V	9.1mV	0.061%
Load regulation	7.9mV 0.053%	5.1mV 0.034%	6.8mV 0.045%	5.6mV 0.037%		

•-Vo

Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	-14.9624V	-14.9634V	-14.9651V	-14.9659V	3.5mV	0.023%
50%(0.05A)	-14.9599V	-14.9585V	-14.9603V	-14.9617V	3.2mV	0.021%
100%(0.1A)	-14.9676V	-14.9627V	-14.9582V	-14.9594V	9.4mV	0.063%
Load regulation	7.7mV 0.051%	4.9mV 0.033%	6.9mV 0.046%	6.5mV 0.043%		

•+Vo to -Vo

Io \ Vin	18VDC	24VDC	48VDC	76VDC	Line regulation	
0%	29.8957V	29.8952V	29.8950V	29.8953V	0.7mV	0.002%
50%(0.05A)	29.8955V	29.8954V	29.8954V	29.8948V	0.7mV	0.002%
100%(0.1A)	29.8953V	29.8950V	29.8949V	29.8944V	0.9mV	0.003%
Load regulation	0.4mV 0.001%	0.4mV 0.001%	0.5mV 0.002%	0.9mV 0.003%		

2. Temperature drift

Conditions Vin : 48 VDC

Io : 100 %

Ta	-40°C	25°C	85°C	Temperature stability	
+Vo	14.9156V	14.9367V	14.8908V	45.9mV	0.306%
-Vo	-14.9324V	-14.9582V	-14.9143V	43.9mV	0.293%
+Vo to -Vo	29.8480V	29.8949V	29.8051V	89.8mV	0.299%

3. Load Regulation - Unbalance load

Condition Ta : 25 °C

•+Vo (-Io : 100%)

+Io \ Vin	18VDC	24VDC	48VDC	76VDC
20%(0.02A)	15.0401V	15.0344V	15.0344V	15.0302V
100%(0.1A)	14.9268V	14.9321V	14.9321V	14.9349V
Load regulation	113.3mV 0.755%	102.3mV 0.682%	102.3mV 0.682%	95.3mV 0.635%

•-Vo (+Io : 100%)

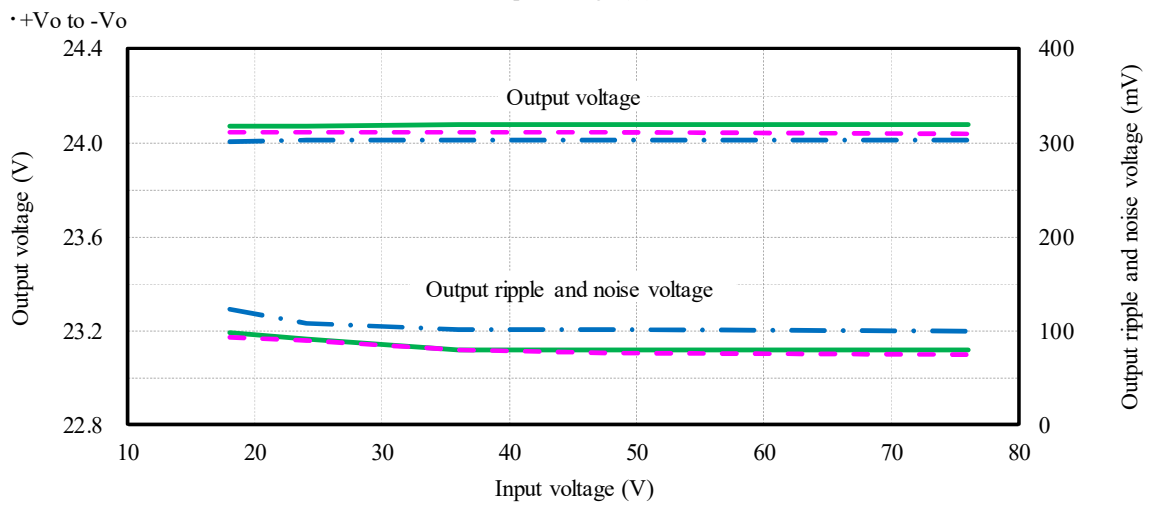
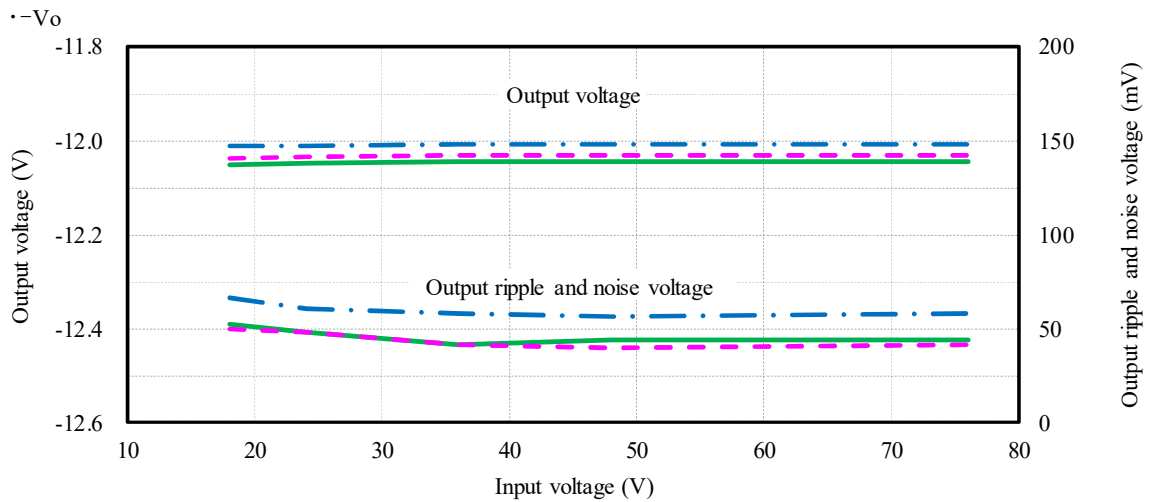
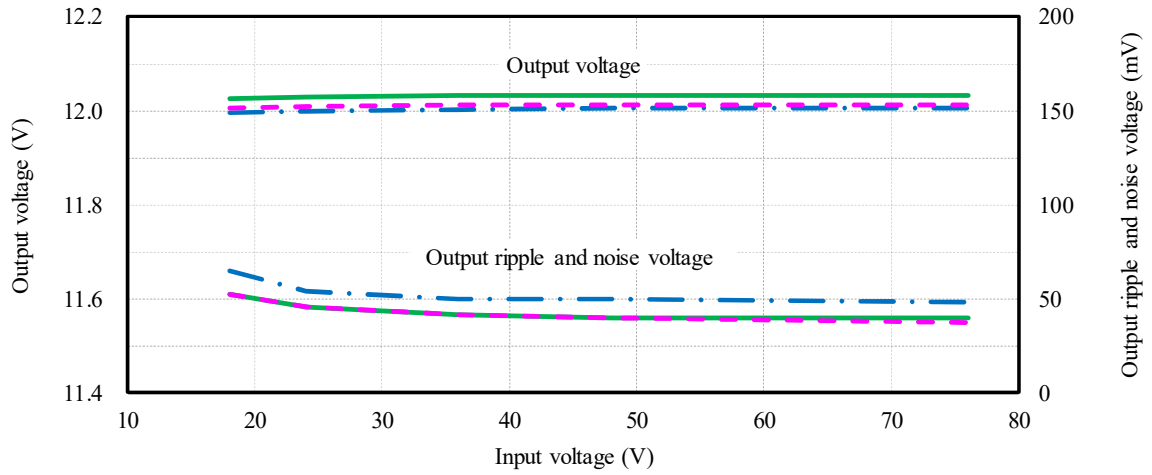
-Io \ Vin	18VDC	24VDC	48VDC	76VDC
20%(0.02A)	-15.0766V	-15.0703V	-15.0703V	-15.0739V
100%(0.1A)	-14.9675V	-14.9627V	-14.9627V	-14.9594V
Load regulation	109.1mV 0.727%	107.6mV 0.717%	107.6mV 0.717%	114.5mV 0.763%

(2) 出力電圧・出力リップルノイズ電圧 対 入力電圧

Output voltage and Output ripple and noise voltage vs. Input voltage

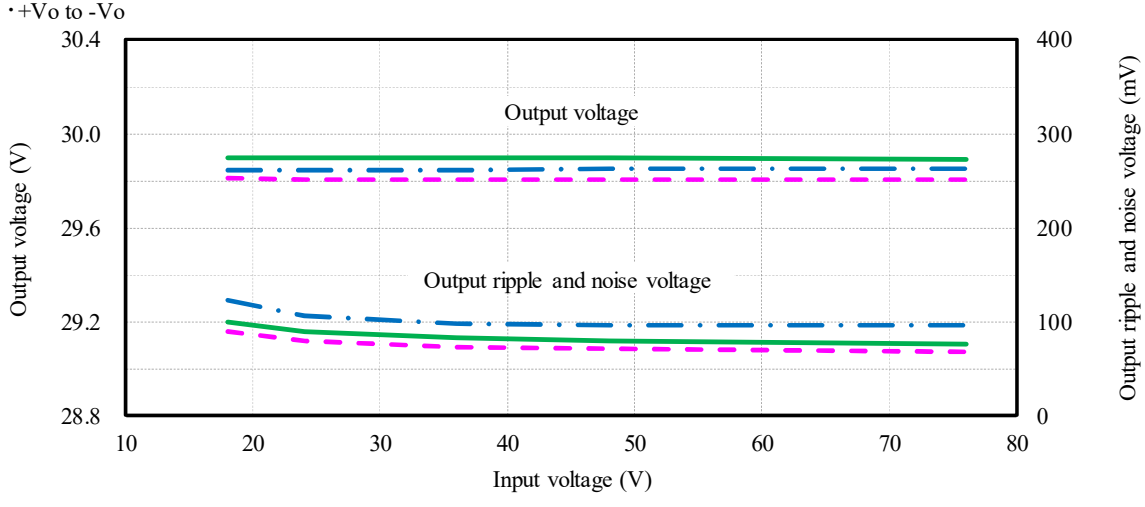
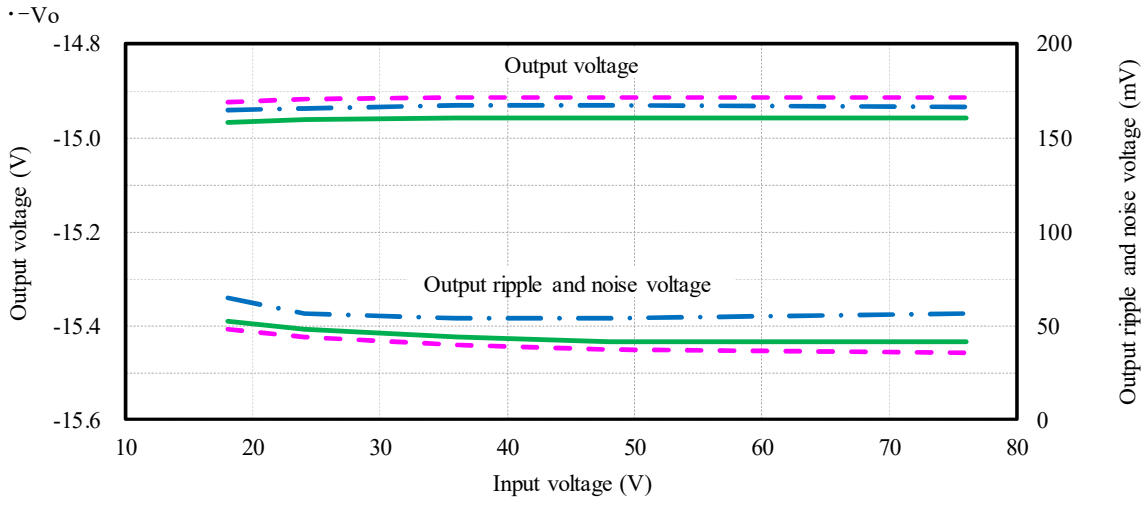
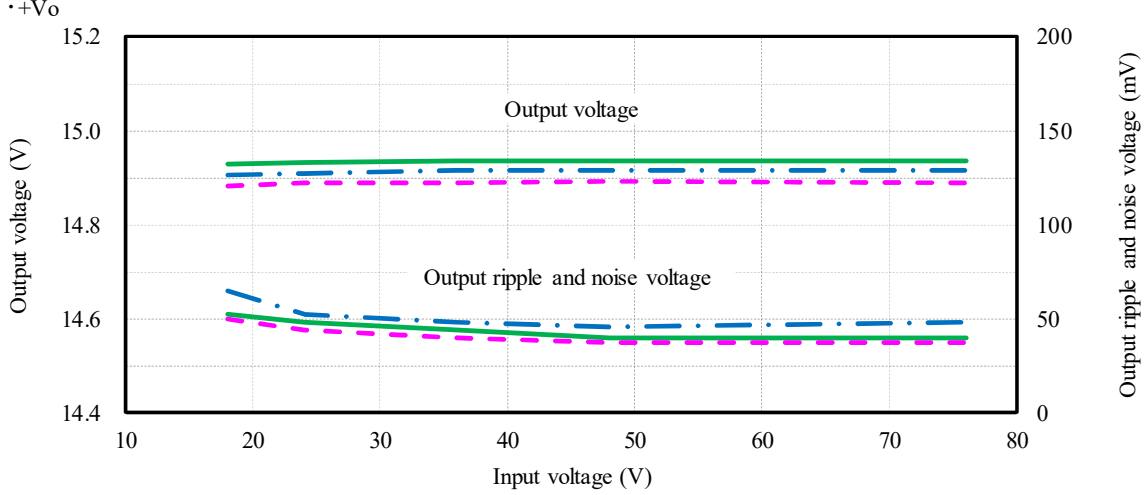
Conditions I_o : 100 %
 T_a : -40 °C
 : 25 °C
 : 85 °C

$\pm 12V$
 • +Vo



Conditions I_o : 100 %
T_a : -40 °C
 : 25 °C
 : 85 °C

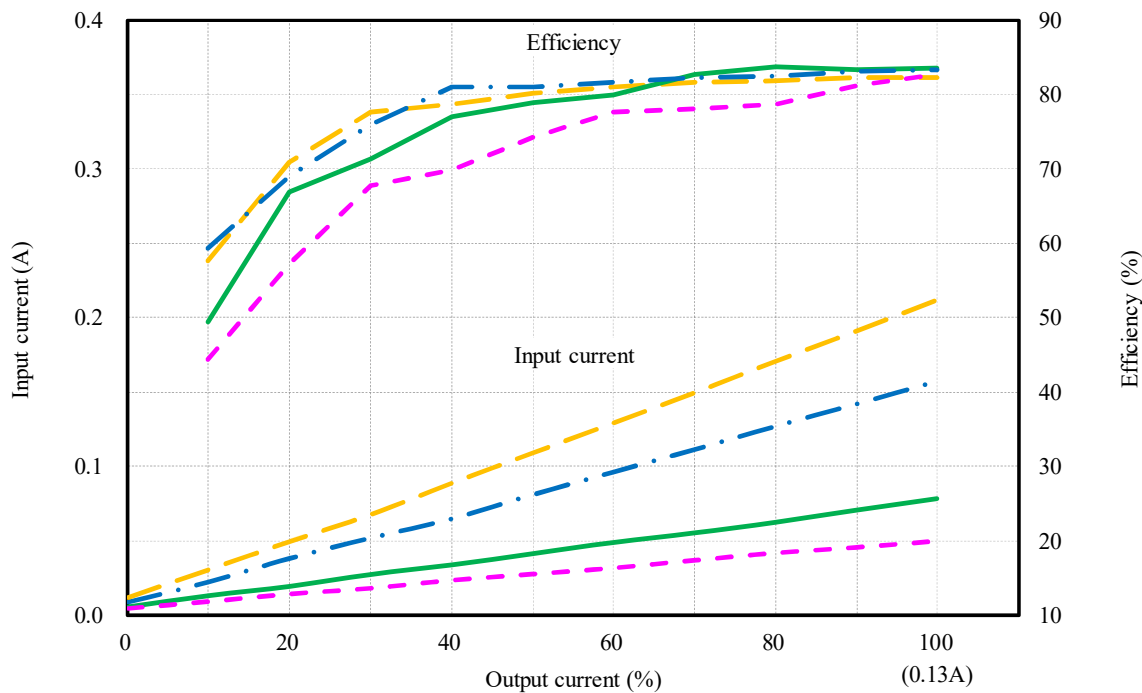
±15V



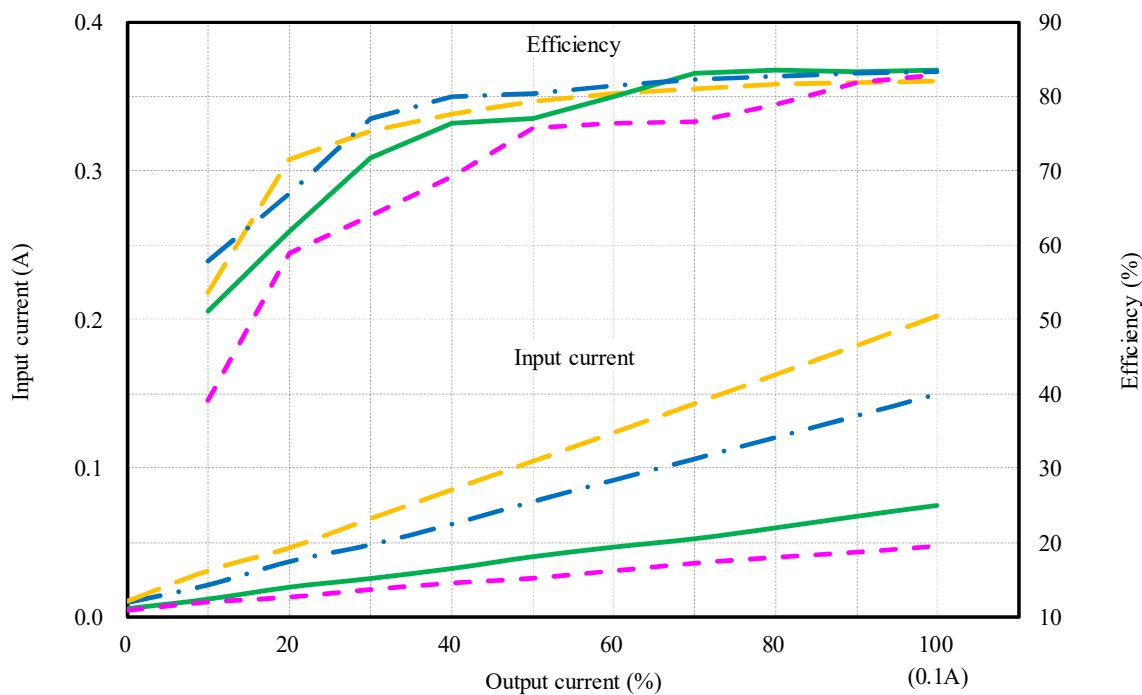
(3) 入力電流・効率 対 出力電流 Input current and Efficiency vs. Output current

Conditions Vin : 18 VDC ————
 : 24 VDC - · - · -
 : 48 VDC ————
 : 76 VDC - · - · -
 Ta : 25 °C

±12V



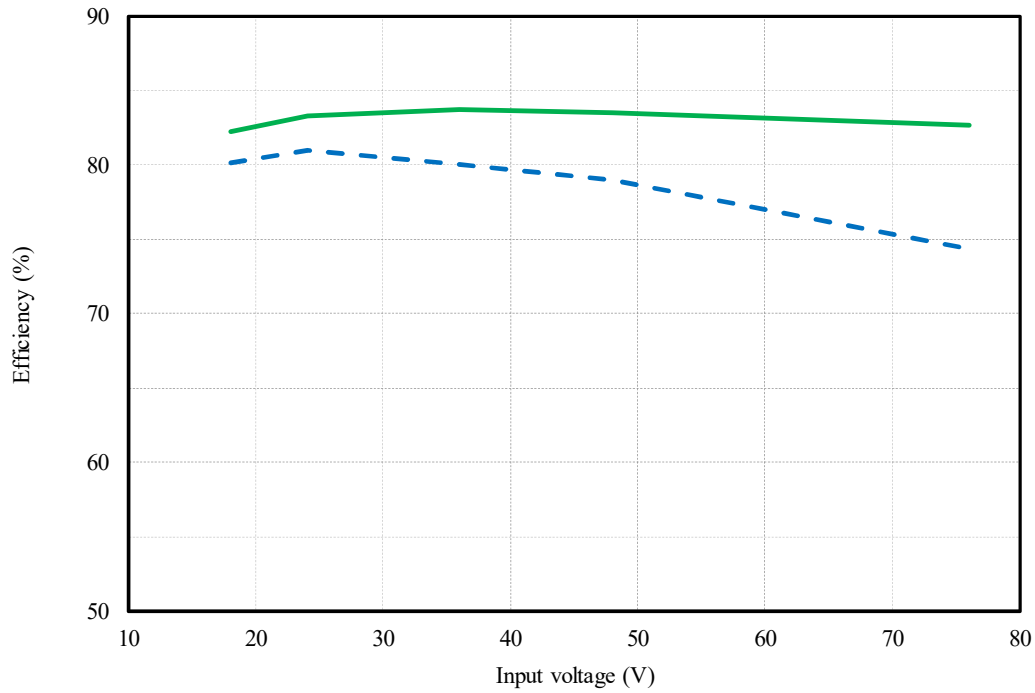
±15V



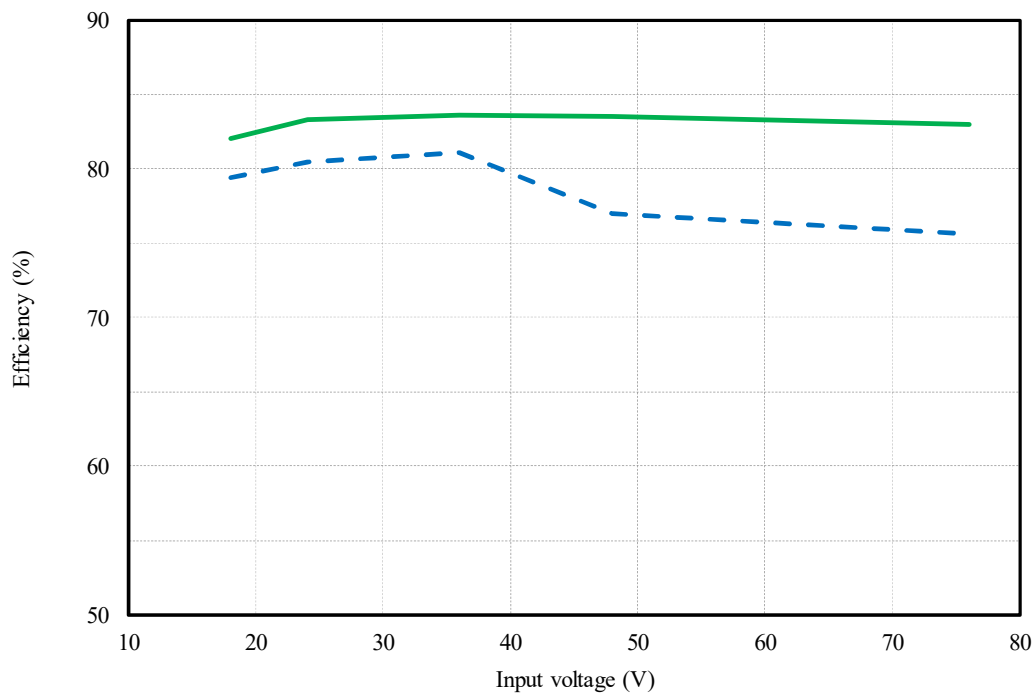
(4) 効率 対 入力電圧 Efficiency vs. Input voltage

Conditions Io : 50 % ---
 : 100 % —
 Ta : 25 °C

±12V



±15V



(5) 起動・遮断電圧特性 Start up and Drop out voltage characteristics

出力電圧 対 入力電圧

Output voltage vs. Input voltage

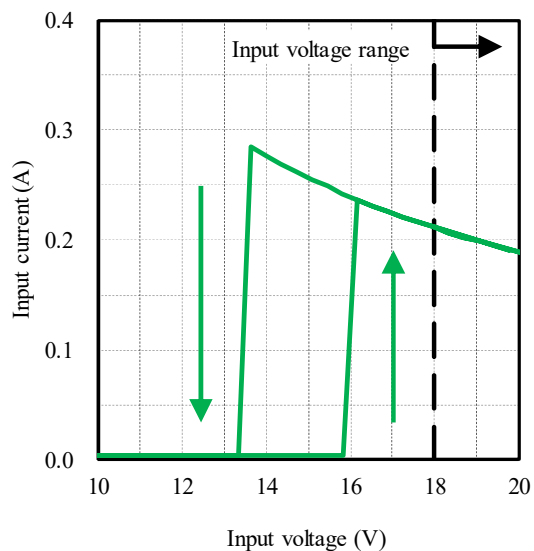
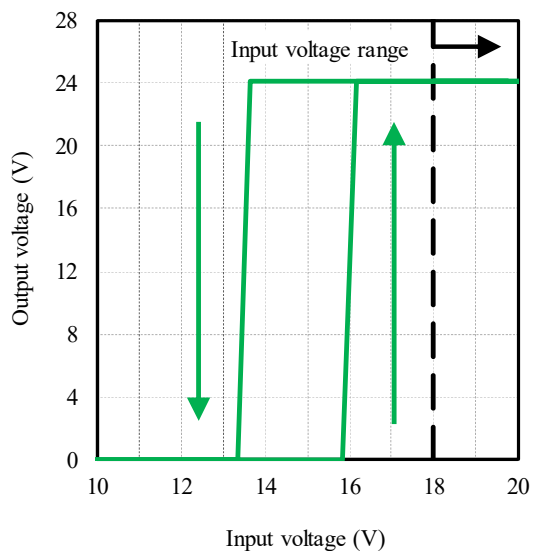
Conditions I_o : 100 %
 T_a : 25 °C

入力電流 対 入力電圧

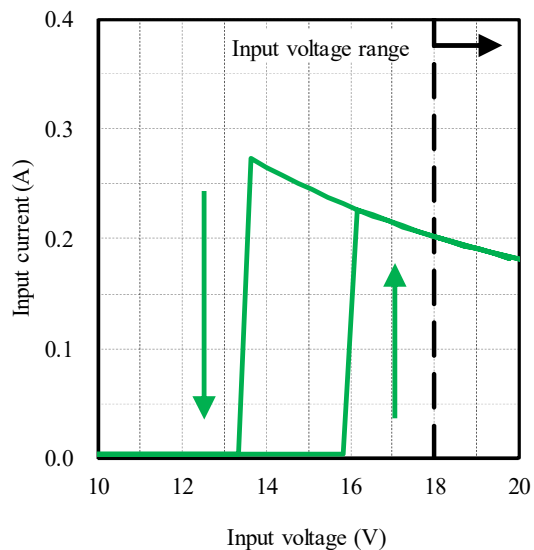
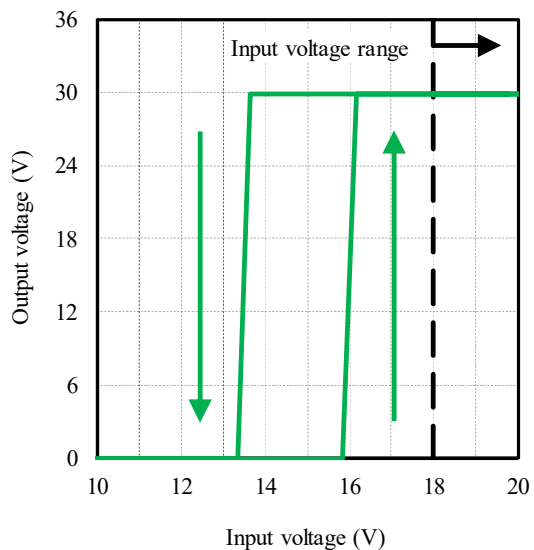
Input current vs. Input voltage

Conditions I_o : 100 %
 T_a : 25 °C

±12V



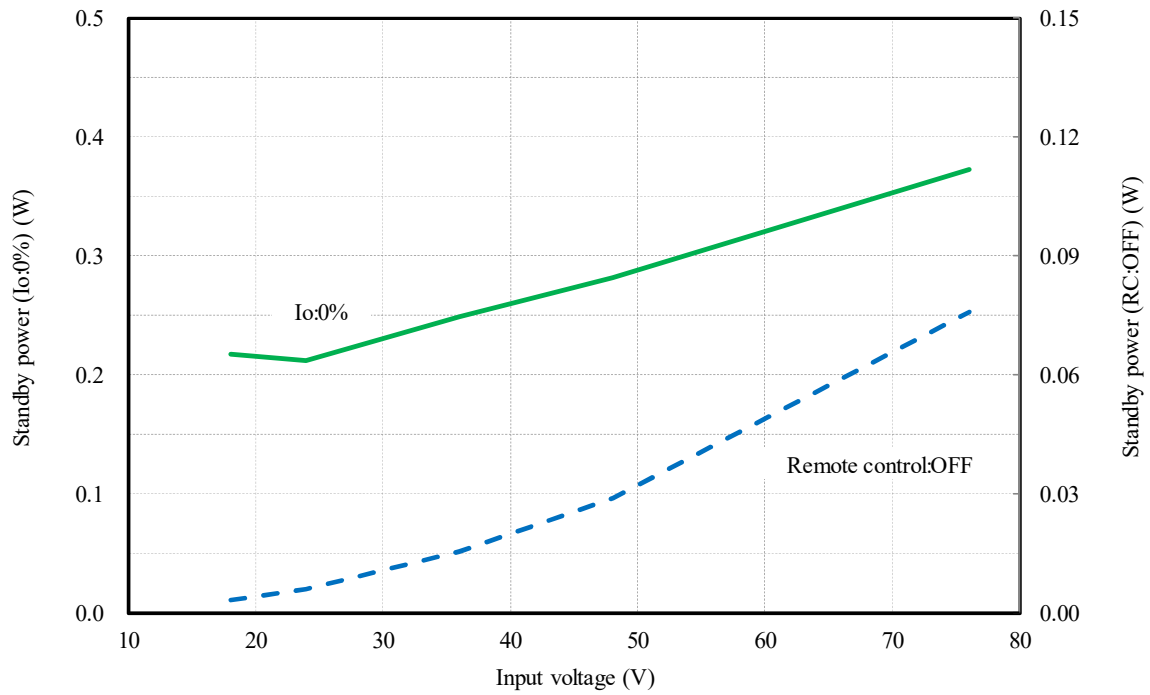
±15V



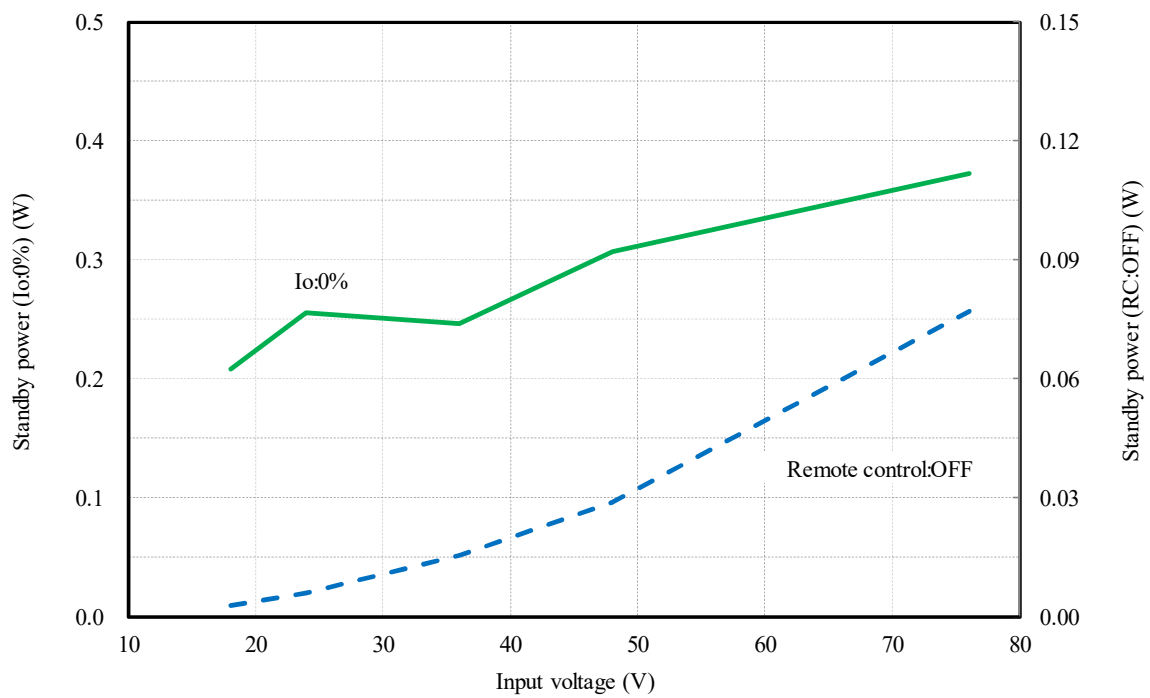
2-2. 待機電力特性 Standby power characteristics

Condition Ta : 25 °C

±12V



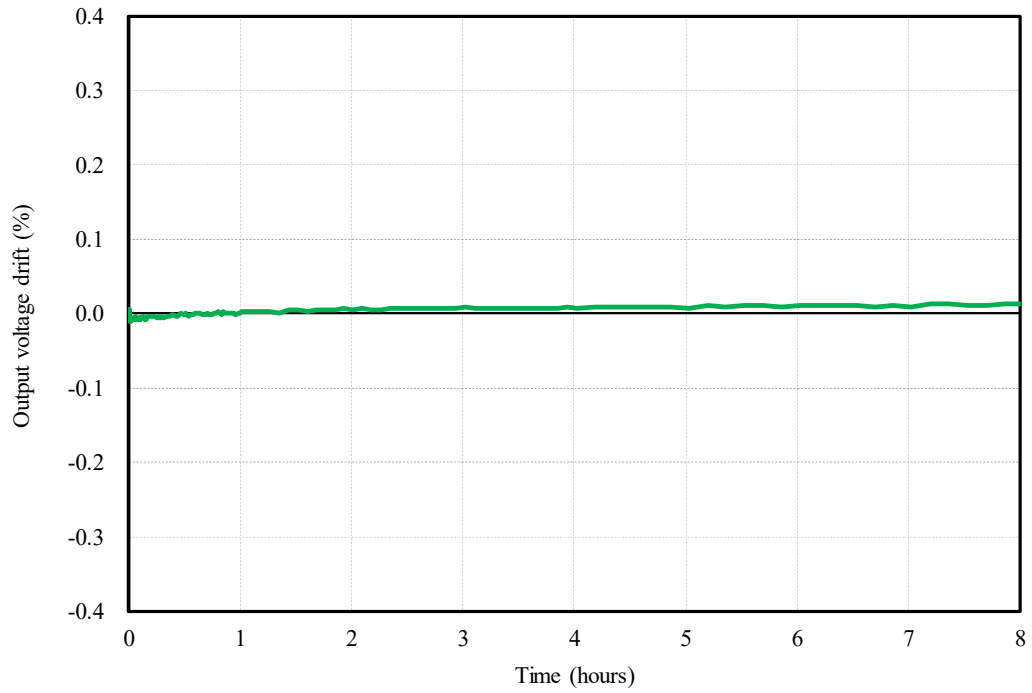
±15V



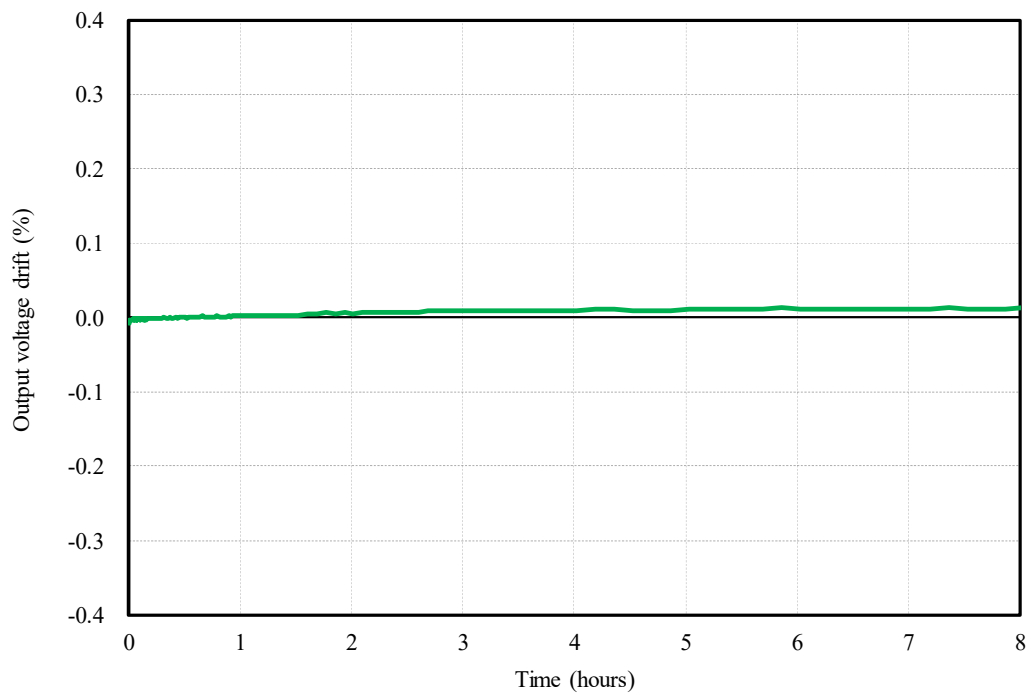
2-3. 通電ドリフト特性 Warm up voltage drift characteristics

Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C

±12V



±15V



2-4. 過電流保護特性 Over current protection (OCP) characteristics

入力電圧依存性

Input voltage dependence

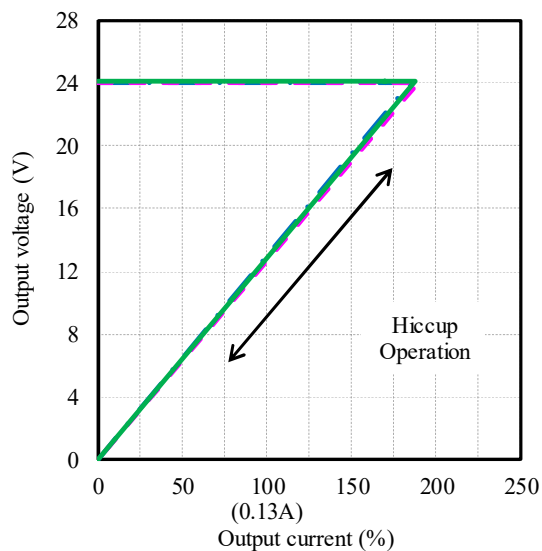
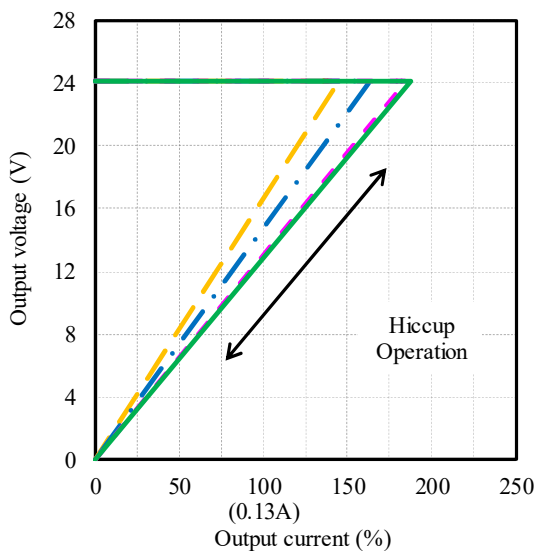
Conditions Vin : 18 VDC ———
 : 24 VDC - - -
 : 48 VDC ———
 : 76 VDC - - -
 Ta : 25 °C

周囲温度依存性

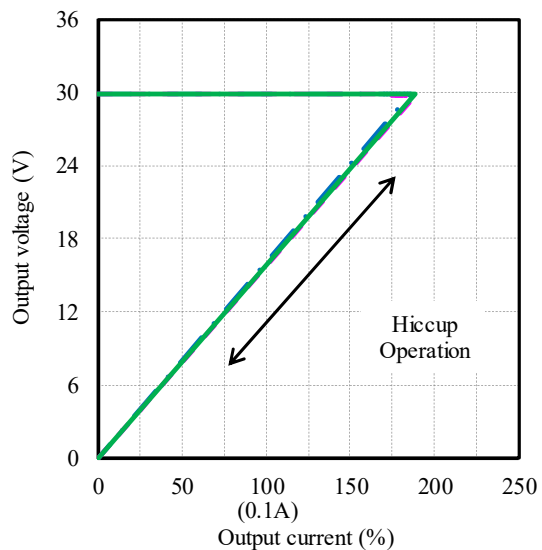
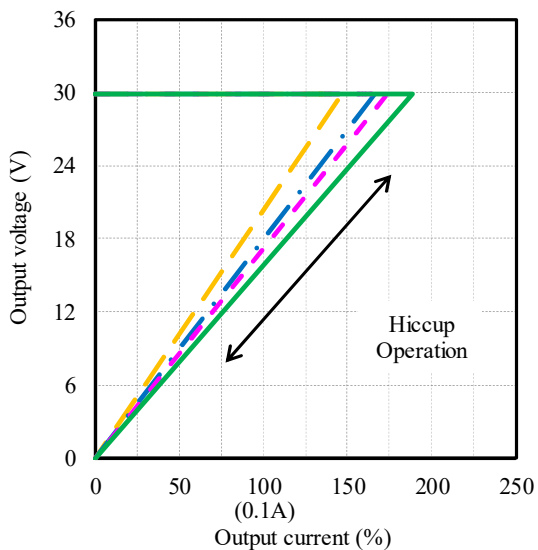
Ambient temperature dependence

Conditions Vin : 48 VDC
 Ta : -40 °C - - -
 : 25 °C ———
 : 85 °C - - -

±12V



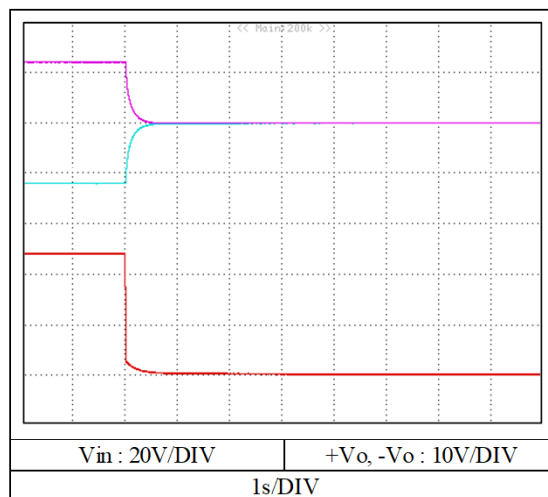
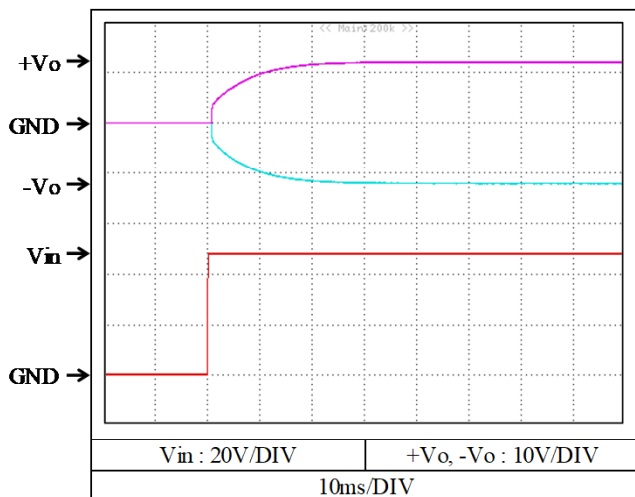
±15V



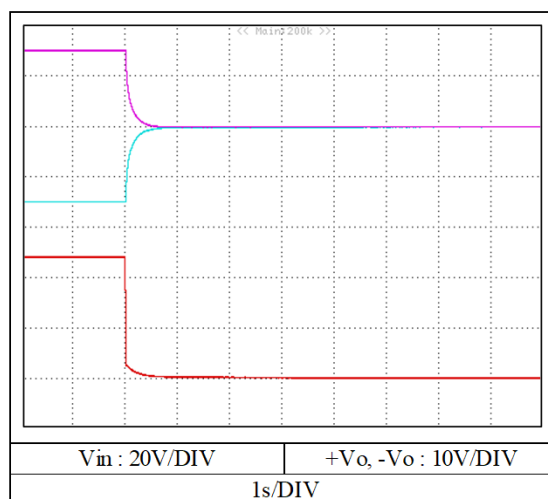
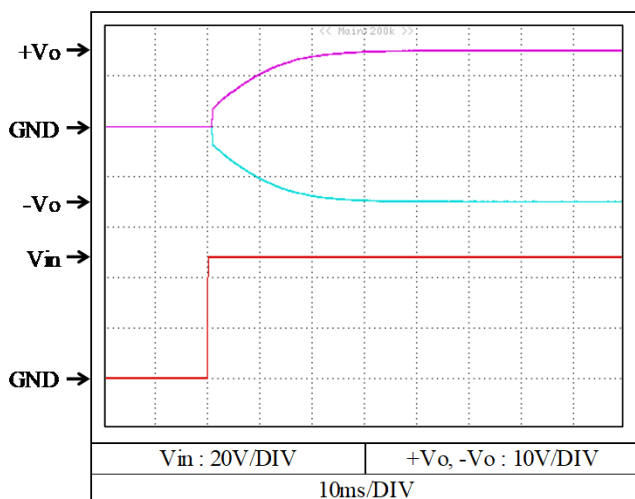
2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics

Conditions V_{in} : 48 VDC
 I_o : 0 %
 T_a : 25 °C

±12V



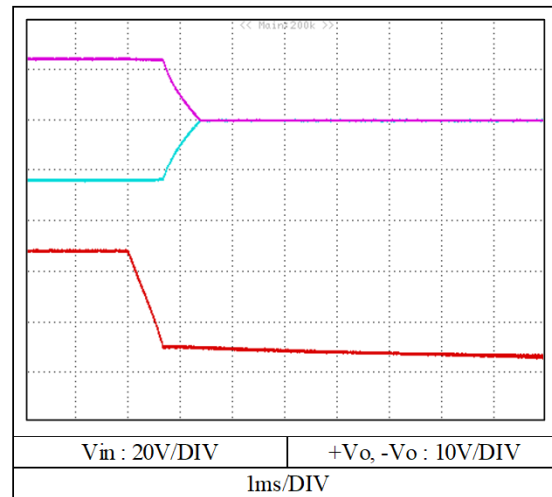
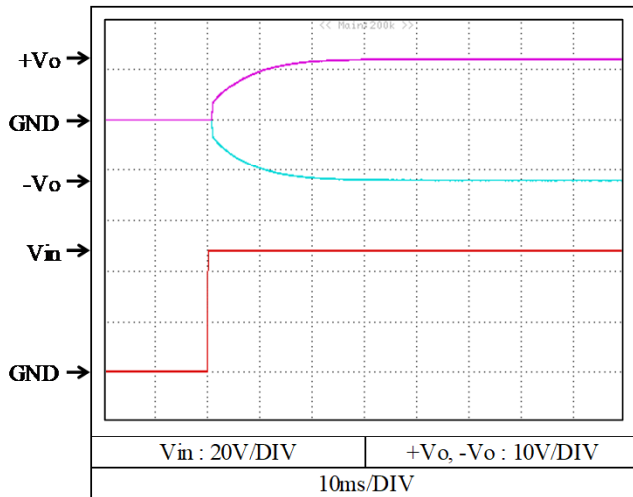
+15V



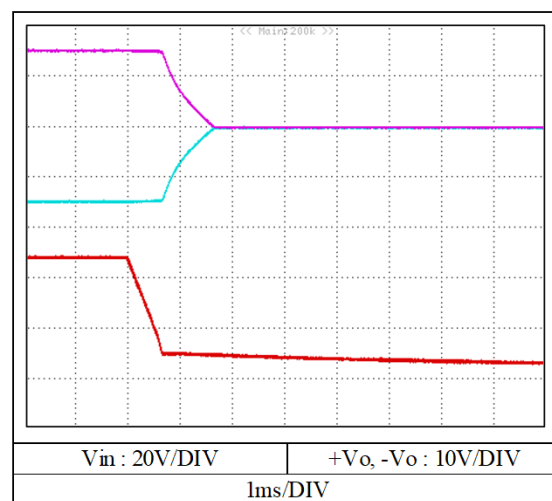
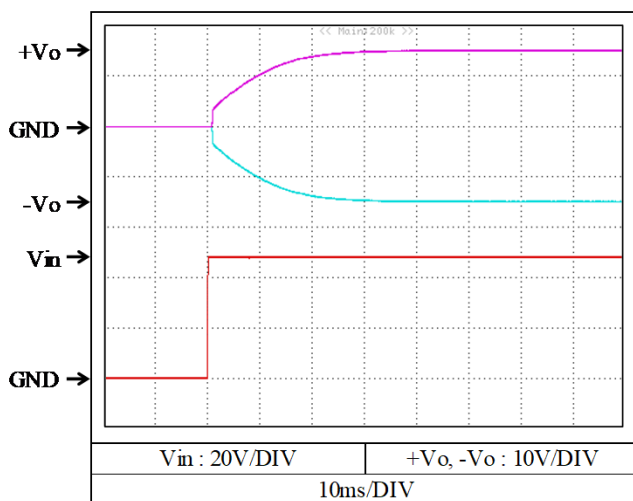
2-5. 出力立ち上がり・立ち下がり特性 Output rise and fall characteristics

Conditions V_{in} : 48 VDC
 I_o : 100 %
 T_a : 25 °C

±12V



+15V

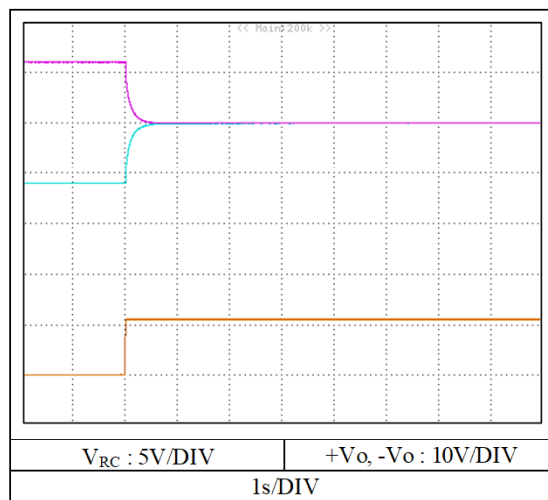
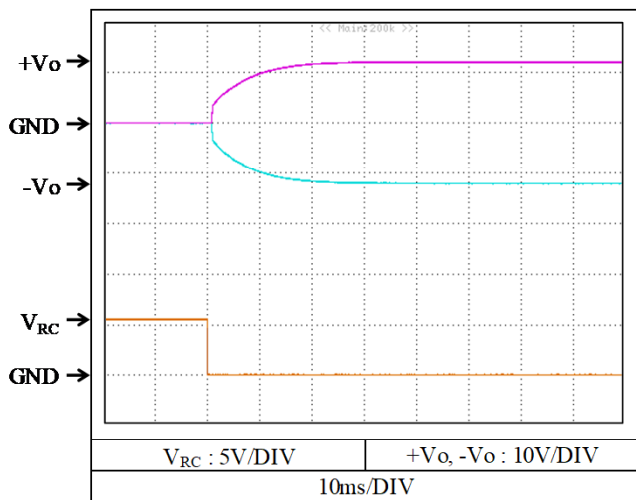


2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)

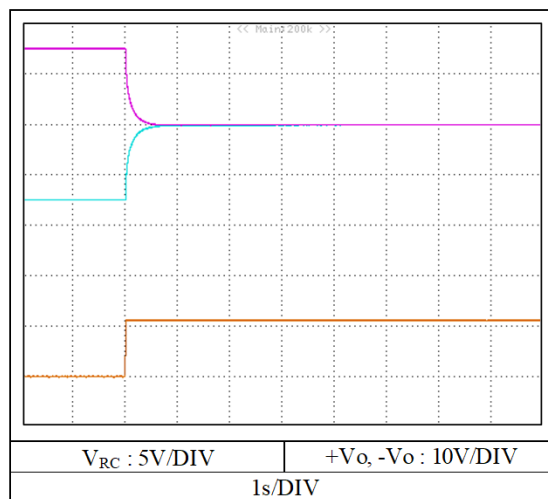
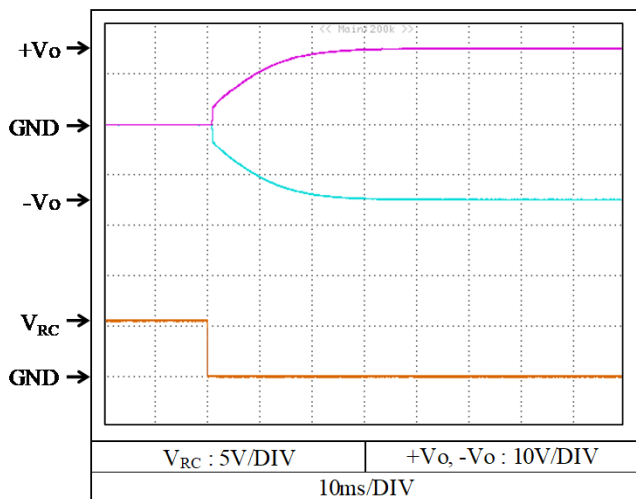
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions V_{in} : 48 VDC
 I_o : 0 %
 T_a : 25 °C

±12V



+15V

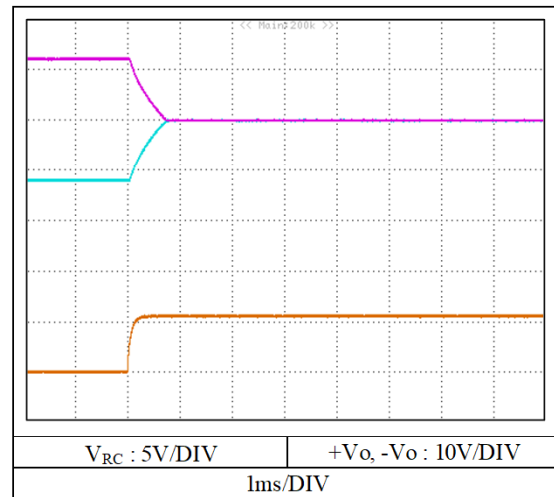
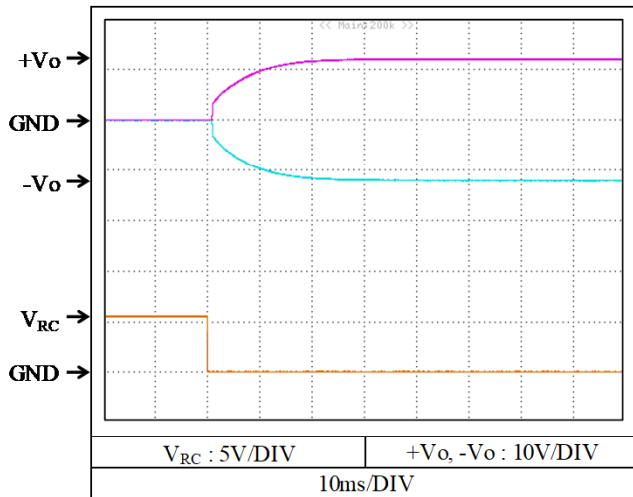


2-5. 出力立ち上がり・立ち下がり特性 (リモートON/OFFコントロール時)

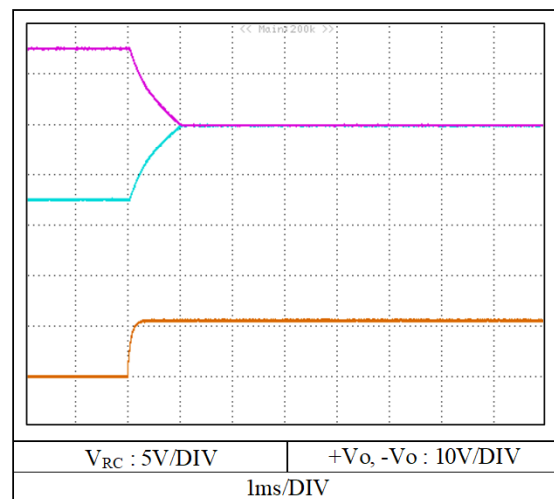
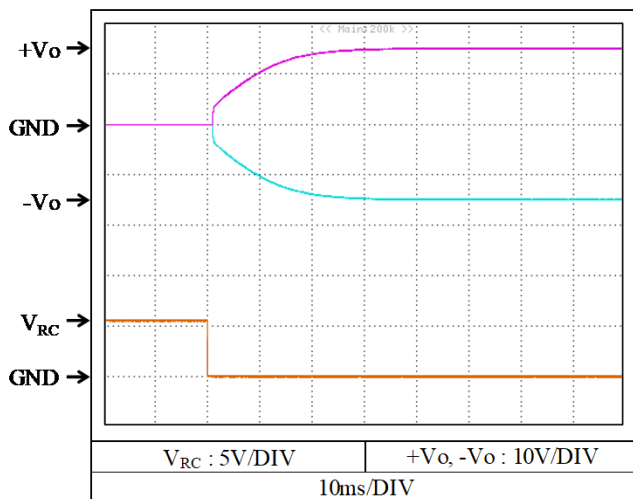
Output rise and fall characteristics with REMOTE ON/OFF CONTROL

Conditions V_{in} : 48 VDC
 I_o : 100 %
 T_a : 25 °C

±12V



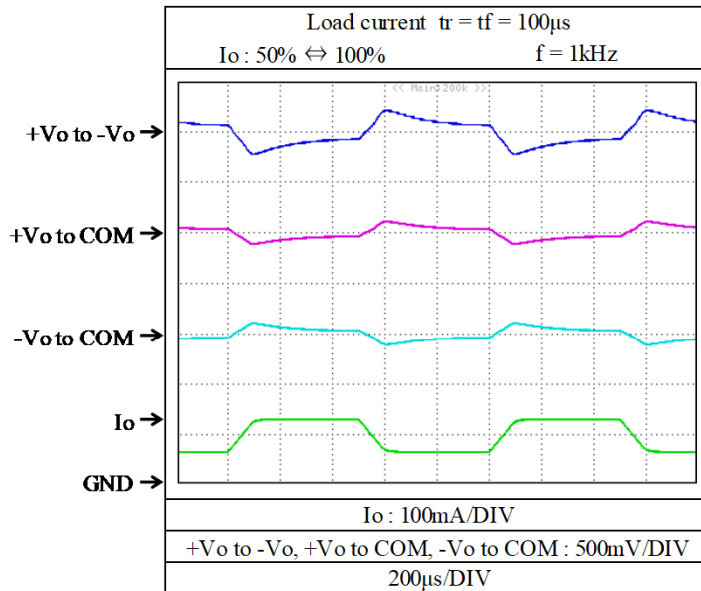
+15V



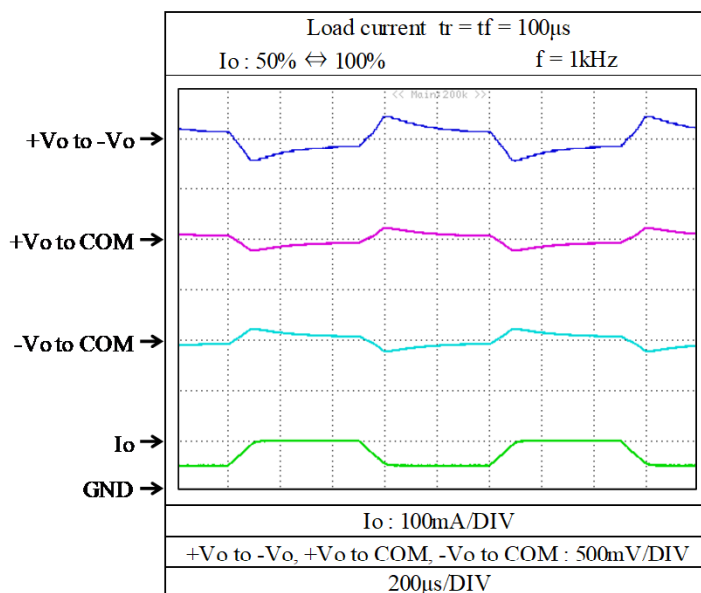
2-6. 過渡応答(負荷急変)特性 Dynamic load response characteristics

Conditions V_{in} : 48 VDC
 T_a : 25 °C

±12V



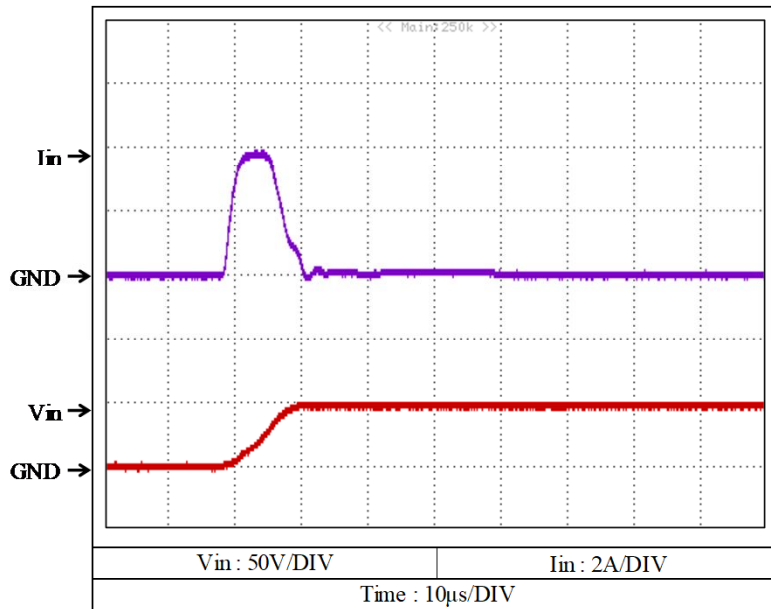
+15V



2-7. 入力サージ電流(突入電流)特性 Inrush current characteristics

Conditions V_{in} : 48 VDC
 I_o : 100 %
 T_a : 25 °C

CCG3-48-05S

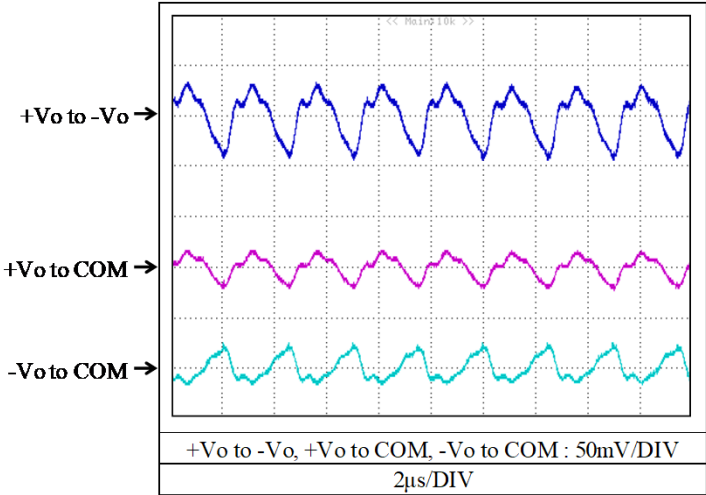


CCG3-48-xxDの入力サージ電流特性は CCG3-48-05S と同等です。
 CCG3-48-xxD have the same Inrush current characteristics as CCG3-48-05S data.

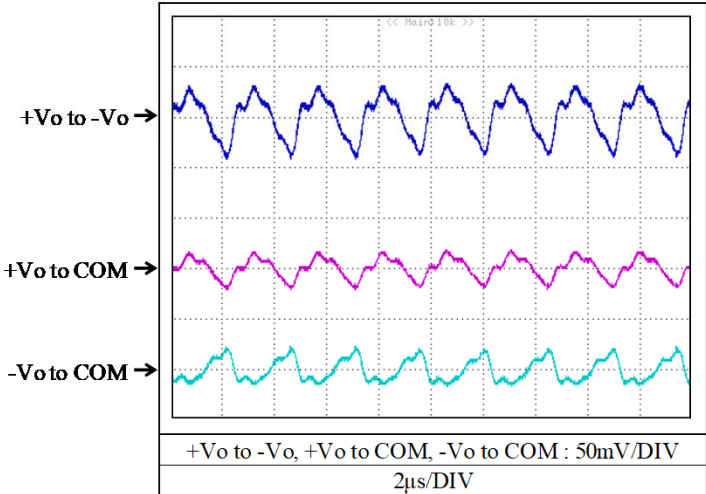
2-8. 出力リップルノイズ波形 Output ripple and noise waveform

Conditions V_{in} : 48 VDC
 I_o : 100 %
 T_a : 25 °C

±12V



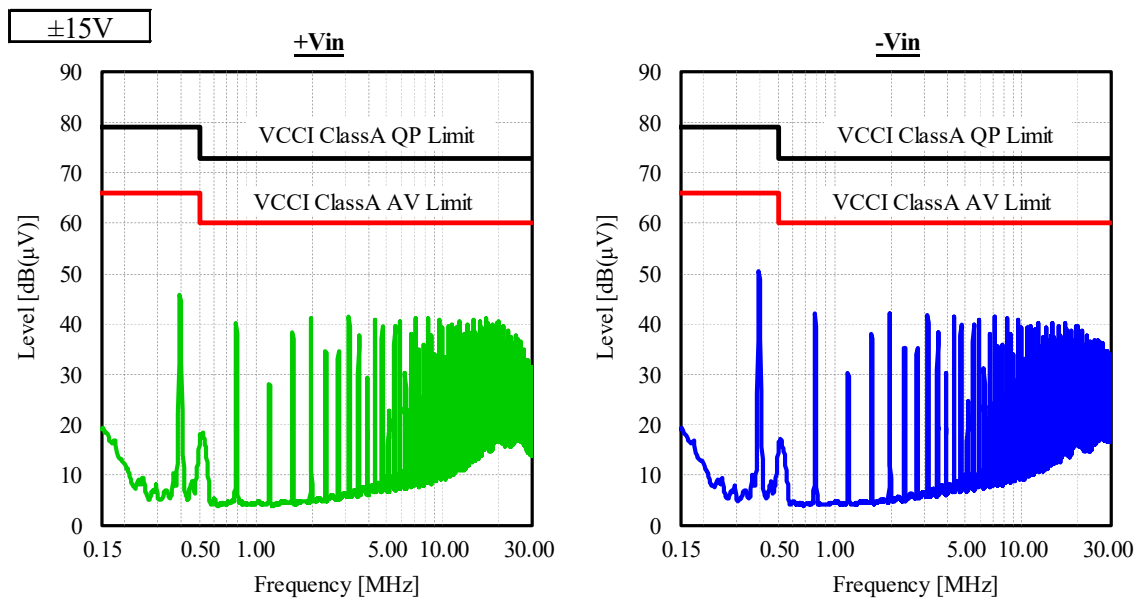
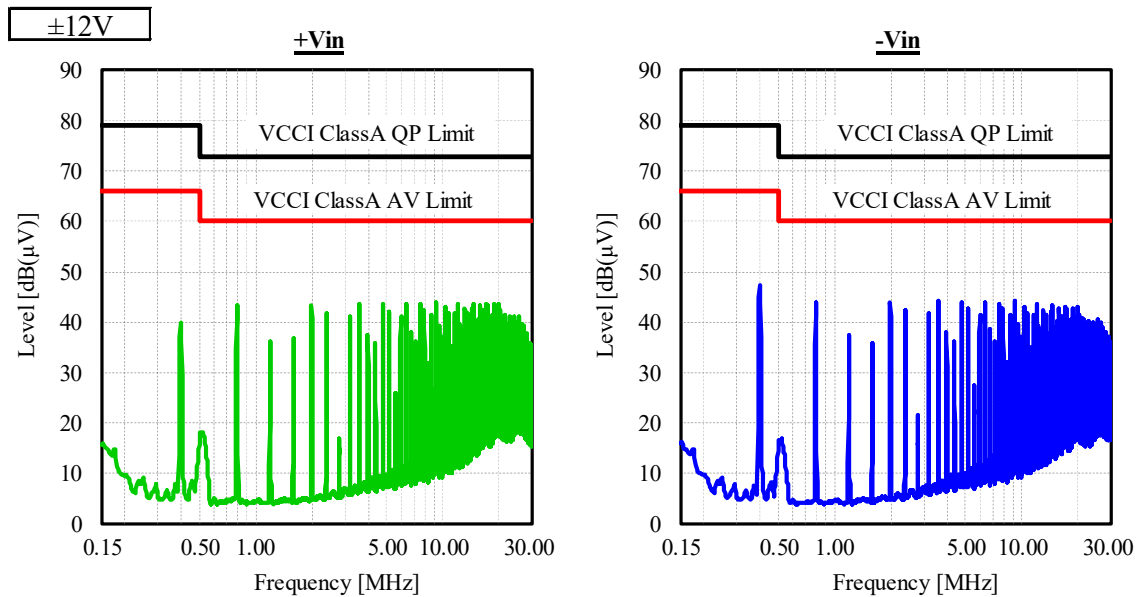
+15V



2-9. EMI特性 Electro-Magnetic Interference characteristics

(a) 雑音端子電圧 (帰還ノイズ) Conducted Emission Noise

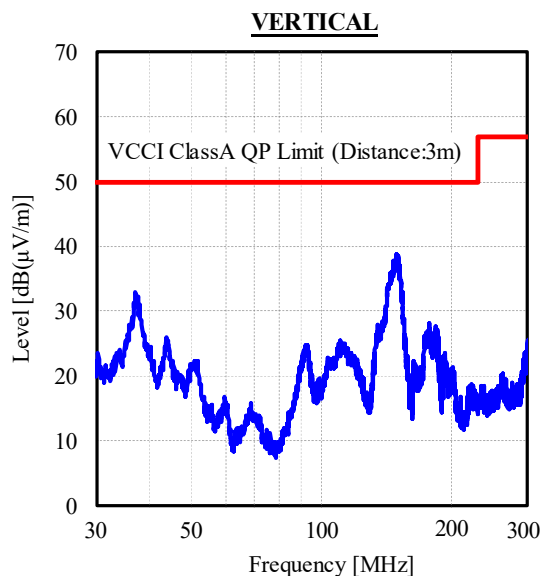
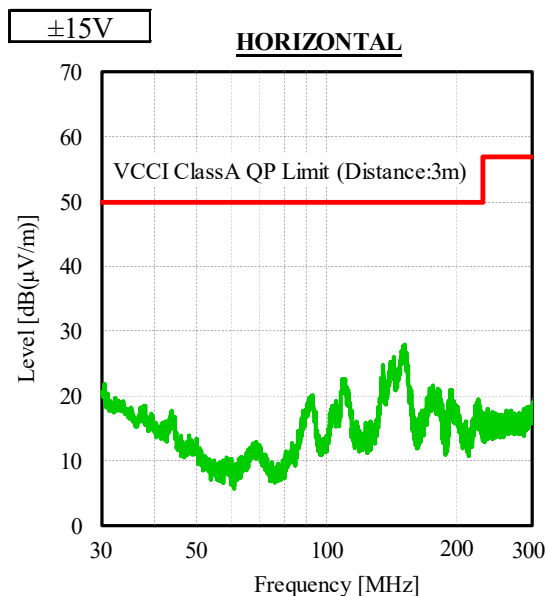
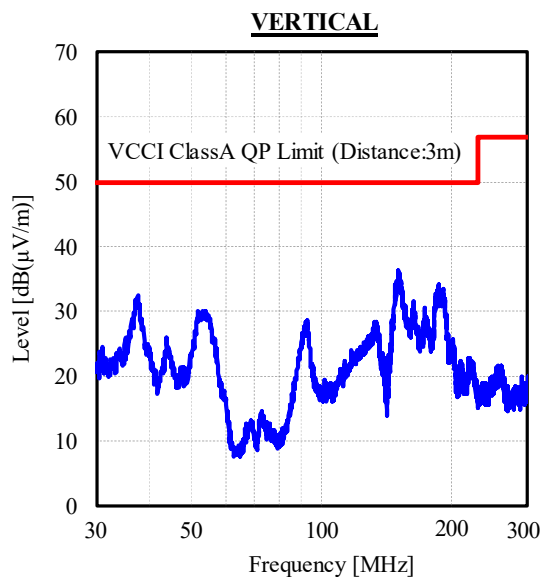
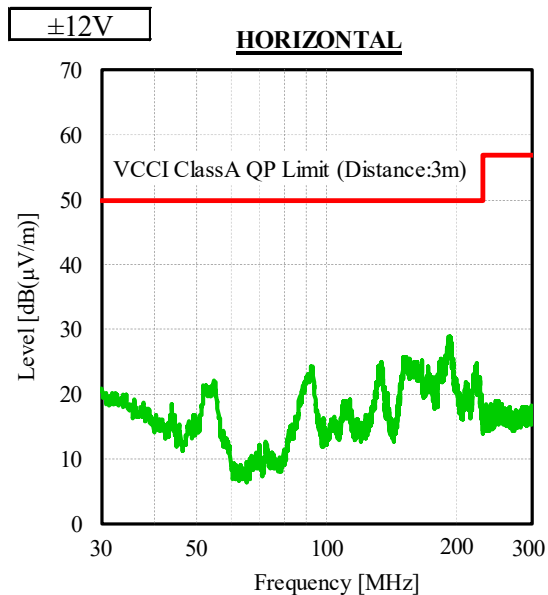
Conditions Vin : 48 VDC
 Io : 100 %
 Ta : 25 °C



表示はQP値
 Indication is QP values.

2-9. EMI特性 Electro-Magnetic Interference characteristics
 (b) 雑音電界強度 (輻射ノイズ) Radiated Emission Noise

Conditions V_{in} : 48 VDC
 I_o : 100 %
 T_a : 25 °C



表示はピーク値
 Indication is peak values.